

APT4020AN 400V 22.5A 0.20  $\Omega$   
 APT3520AN 350V 22.5A 0.20  $\Omega$   
 APT4025AN 400V 20.0A 0.25  $\Omega$   
 APT3525AN 350V 20.0A 0.25  $\Omega$

## POWER MOS IV™

### N - CHANNEL ENHANCEMENT MODE HIGH VOLTAGE POWER MOSFETS

#### MAXIMUM RATINGS

All Ratings:  $T_C = 25^\circ\text{C}$  unless otherwise specified.

| Symbol                            | Parameter                                                             | APT         |        |        |        | UNIT  |
|-----------------------------------|-----------------------------------------------------------------------|-------------|--------|--------|--------|-------|
|                                   |                                                                       | 3520AN      | 4020AN | 3525AN | 4025AN |       |
| V <sub>DSS</sub>                  | Drain-Source Voltage                                                  | 350         | 400    | 350    | 400    | Volts |
| I <sub>D</sub>                    | Continuous Drain Current                                              | 22.5        |        | 20     |        | Amps  |
| I <sub>DM</sub>                   | Pulsed Drain Current <sup>1</sup>                                     | 90          |        | 80     |        | Amps  |
| V <sub>GS</sub>                   | Gate-Source Voltage                                                   | ±30         |        |        |        | Volts |
| P <sub>D</sub>                    | Total Power Dissipation @ T <sub>C</sub> = 25°C,<br>Derate Above 25°C | 230         |        |        |        | Watts |
| T <sub>J</sub> , T <sub>STG</sub> | Operating and Storage Junction Temperature Range                      | - 55 to 150 |        |        |        | °C    |

#### STATIC ELECTRICAL CHARACTERISTICS

| Symbol       | Characteristic / Test Conditions / Part Number                                                                                          |                       | MIN  | TYP | MAX       | UNIT    |
|--------------|-----------------------------------------------------------------------------------------------------------------------------------------|-----------------------|------|-----|-----------|---------|
| $BV_{DSS}$   | Drain-Source Breakdown Voltage<br>( $V_{GS} = 0V, I_D = 250 \mu A$ )                                                                    | APT4020AN / APT4025AN | 400  |     |           | Volts   |
|              |                                                                                                                                         | APT3520AN / APT3525AN | 350  |     |           | Volts   |
| $I_{DSS}$    | Zero Gate Voltage Drain Current ( $V_{DS} = V_{DSS}, V_{GS} = 0V$ )<br>( $V_{DS} = 0.8 V_{DSS}, V_{GS} = 0V, T_C = 125^\circ\text{C}$ ) |                       |      |     | 250       | $\mu A$ |
|              |                                                                                                                                         |                       |      |     | 1000      |         |
| $I_{GSS}$    | Gate-Source Leakage Current ( $V_{GS} = \pm 30V, V_{DS} = 0V$ )                                                                         |                       |      |     | $\pm 100$ | nA      |
| $I_{D(ON)}$  | On State Drain Current <sup>2</sup><br>( $V_{DS} > I_{D(ON)} \times R_{DS(ON)}$ Max, $V_{GS} = 10V$ )                                   | APT4020AN / APT3520AN | 22.5 |     |           | Amps    |
|              |                                                                                                                                         | APT4025AN / APT3525AN | 20   |     |           | Amps    |
| $V_{GS(TH)}$ | Gate Threshold Voltage ( $V_{DS} = V_{GS}, I_D = 1mA$ )                                                                                 |                       | 2    |     | 4         | Volts   |
| $R_{DS(ON)}$ | Static Drain-Source On-State Resistance <sup>2</sup><br>( $V_{GS} = 10V, I_D = 0.5 I_{D(ON)}$ [Cont.])                                  | APT4020AN / APT3520AN |      |     | 0.20      | Ohms    |
|              |                                                                                                                                         | APT4025AN / APT3525AN |      |     | 0.25      | Ohms    |

#### THERMAL CHARACTERISTICS

| Symbol          | Characteristic                                                         | MIN | TYP | MAX  | UNIT               |
|-----------------|------------------------------------------------------------------------|-----|-----|------|--------------------|
| $R_{\theta JC}$ | Junction to Case                                                       |     |     | 0.53 | $^\circ\text{C/W}$ |
| $R_{\theta JA}$ | Junction to Ambient                                                    |     |     | 30   | $^\circ\text{C/W}$ |
| $T_L$           | Max. Lead Temp. for Soldering Conditions: 0.063" from Case for 10 Sec. |     |     | 300  | $^\circ\text{C}$   |

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# DYNAMIC CHARACTERISTICS

APT4020/3520/4025/3525AN

| Symbol       | Characteristic                 | Test Conditions                                                                         | MIN | TYP  | MAX  | UNIT |
|--------------|--------------------------------|-----------------------------------------------------------------------------------------|-----|------|------|------|
| $C_{iss}$    | Input Capacitance              | $V_{GS} = 0V$<br>$V_{DS} = 25V$<br>$f = 1 \text{ MHz}$                                  |     | 2380 | 2950 | pF   |
| $C_{oss}$    | Output Capacitance             |                                                                                         |     | 563  | 750  | pF   |
| $C_{rss}$    | Reverse Transfer Capacitance   |                                                                                         |     | 207  | 310  | pF   |
| $Q_g$        | Total Gate Charge <sup>3</sup> | $V_{GS} = 10V, I_D = I_D [\text{Cont.}]$<br>$V_{DD} = 0.5 V_{DSS}$                      |     | 94   | 130  | nC   |
| $Q_{gs}$     | Gate-Source Charge             |                                                                                         |     | 11   | 16   | nC   |
| $Q_{gd}$     | Gate-Drain ("Miller") Charge   |                                                                                         |     | 47   | 70   | nC   |
| $t_{d(on)}$  | Turn-on Delay Time             | $V_{DD} = 0.5 V_{DSS}$<br>$I_D = I_D [\text{Cont.}], V_{GS} = 15V$<br>$R_G = 1.8\Omega$ |     | 14   | 28   | ns   |
| $t_r$        | Rise Time                      |                                                                                         |     | 29   | 57   | ns   |
| $t_{d(off)}$ | Turn-off Delay Time            |                                                                                         |     | 60   | 90   | ns   |
| $t_f$        | Fall Time                      |                                                                                         |     | 40   | 80   | ns   |

# SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS

T-39-15

| Symbol   | Characteristic / Test Conditions / Part Number                                  | MIN                   | TYP | MAX  | UNIT    |
|----------|---------------------------------------------------------------------------------|-----------------------|-----|------|---------|
| $I_S$    | Continuous Source Current (Body Diode)                                          | APT4020AN / APT3520AN |     | 22.5 | Amps    |
|          |                                                                                 | APT4025AN / APT3525AN |     | 20   | Amps    |
| $I_{SM}$ | Pulsed Source Current <sup>1</sup> (Body Diode)                                 | APT4020AN / APT3520AN |     | 90   | Amps    |
|          |                                                                                 | APT4025AN / APT3525AN |     | 80   | Amps    |
| $V_{SD}$ | Diode Forward Voltage <sup>2</sup> ( $V_{GS} = 0V, I_S = -I_D [\text{Cont.}]$ ) |                       |     | 1.3  | Volts   |
| $t_{rr}$ | Reverse Recovery Time ( $I_S = -I_D [\text{Cont.}], di_S/dt = 100A/\mu s$ )     | 180                   | 360 | 720  | ns      |
| $Q_{rr}$ | Reverse Recovery Charge                                                         | 3                     | 6   | 12   | $\mu C$ |

# SAFE OPERATING AREA CHARACTERISTICS

| Symbol   | Characteristic            | Test Conditions / Part Number                                                        | MIN | TYP | MAX | UNIT  |
|----------|---------------------------|--------------------------------------------------------------------------------------|-----|-----|-----|-------|
| SOA1     | Safe Operating Area       | $V_{DS} = 0.4 V_{DSS}, I_{DS} = P_D / 0.4 V_{DSS}, t = 1 \text{ Sec.}$               | 230 |     |     | Watts |
| SOA2     | Safe Operating Area       | $I_{DS} = I_D [\text{Cont.}], V_{DS} = P_D / I_D [\text{Cont.}], t = 1 \text{ Sec.}$ | 230 |     |     | Watts |
| $I_{LM}$ | Inductive Current Clamped | APT4020AN / APT3520AN                                                                | 90  |     |     | Amps  |
|          |                           | APT4025AN / APT3525AN                                                                | 80  |     |     | Amps  |

1.) Repetitive Rating: Pulse width limited by maximum junction temperature. See Transient Thermal Impedance Curve. (Fig.1)

2.) Pulse Test: Pulse width < 380  $\mu s$   
Duty Cycle < 2%  
3.) See MIL-STD-750 Method 3471

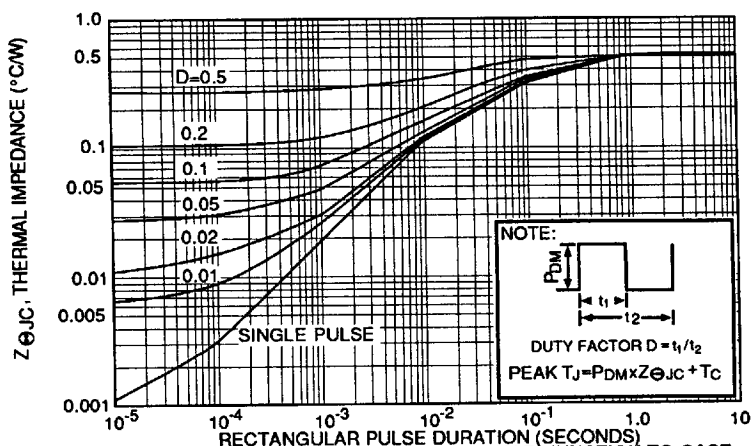
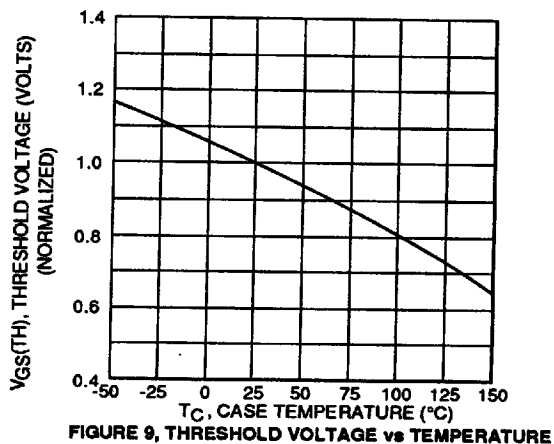
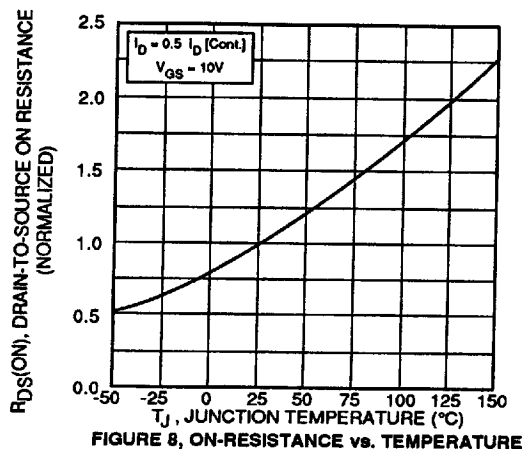
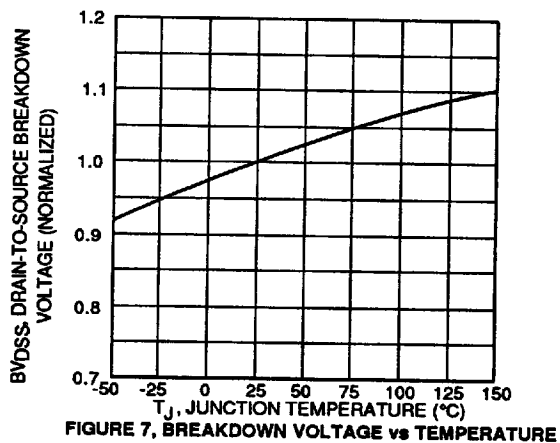
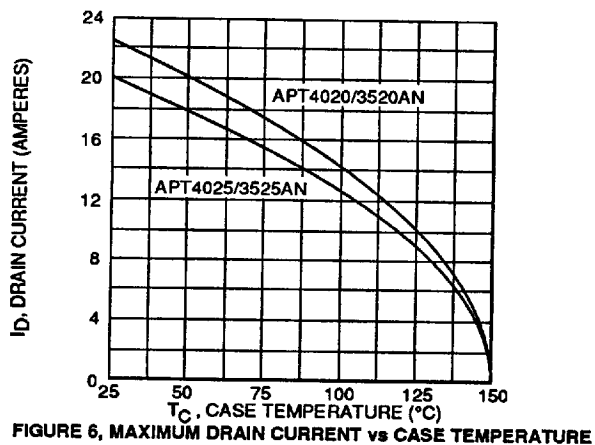
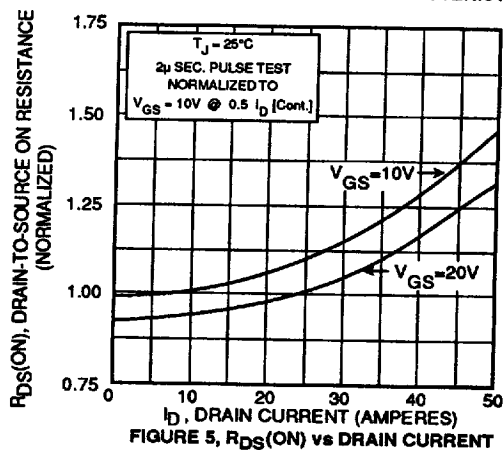
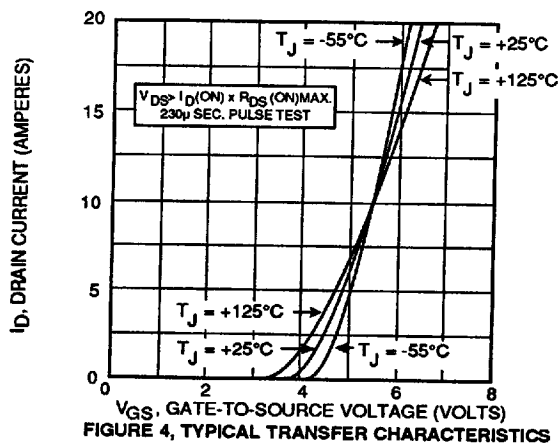
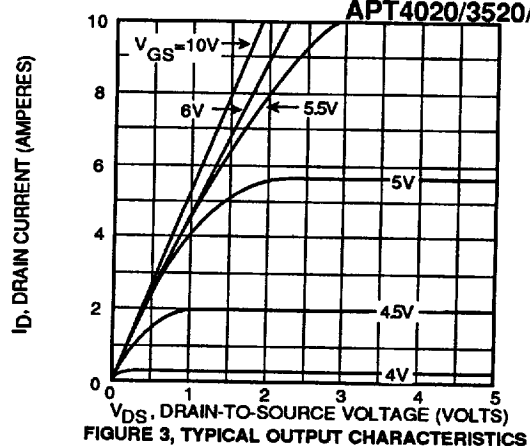
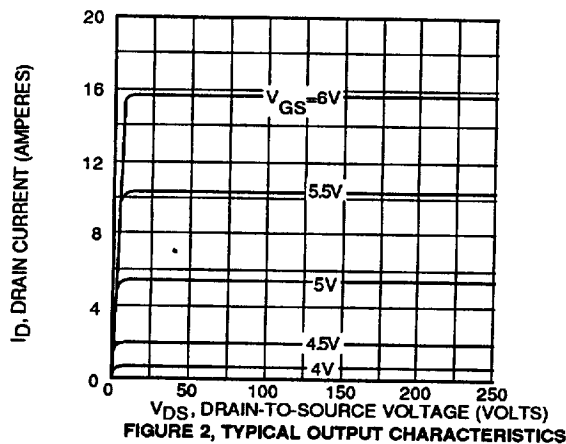
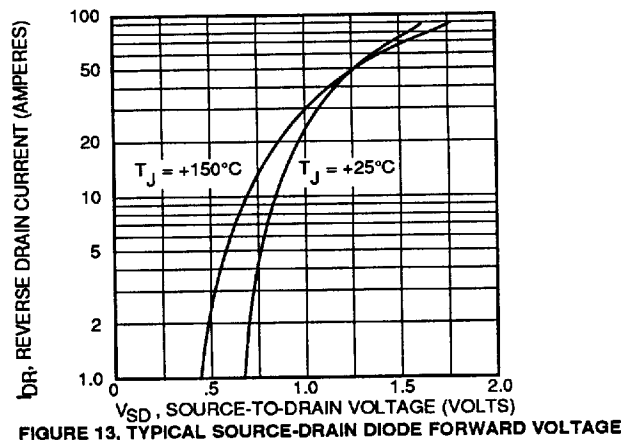
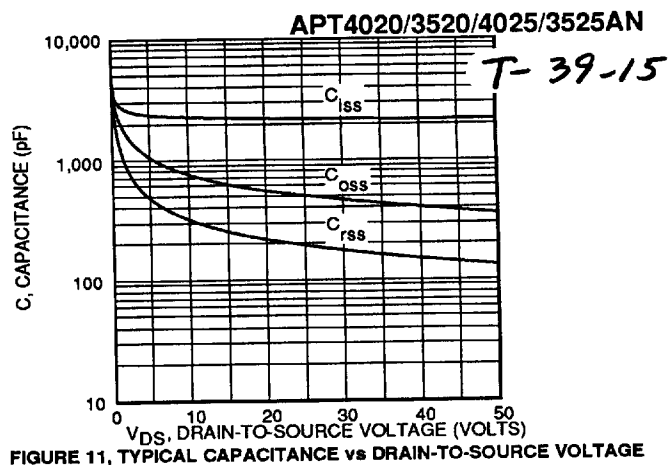
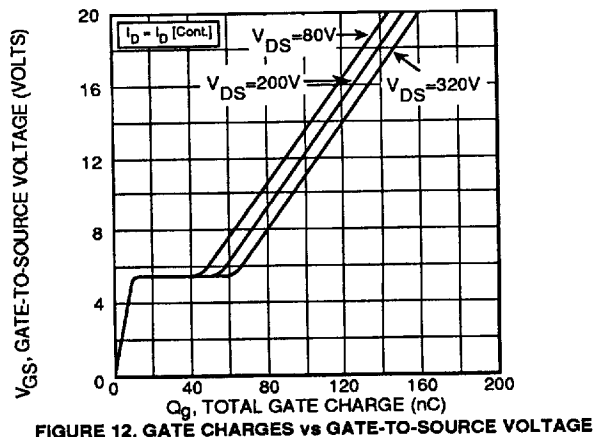
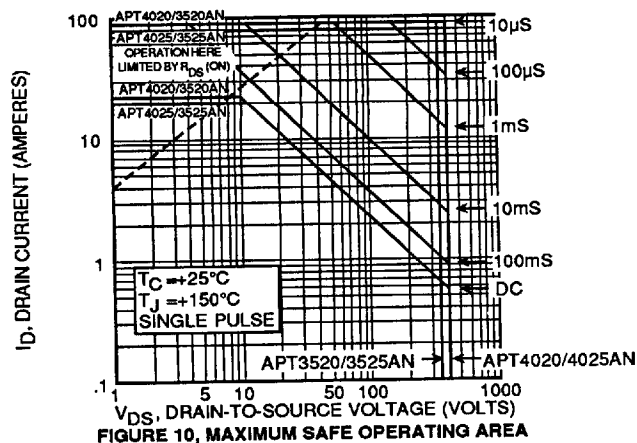
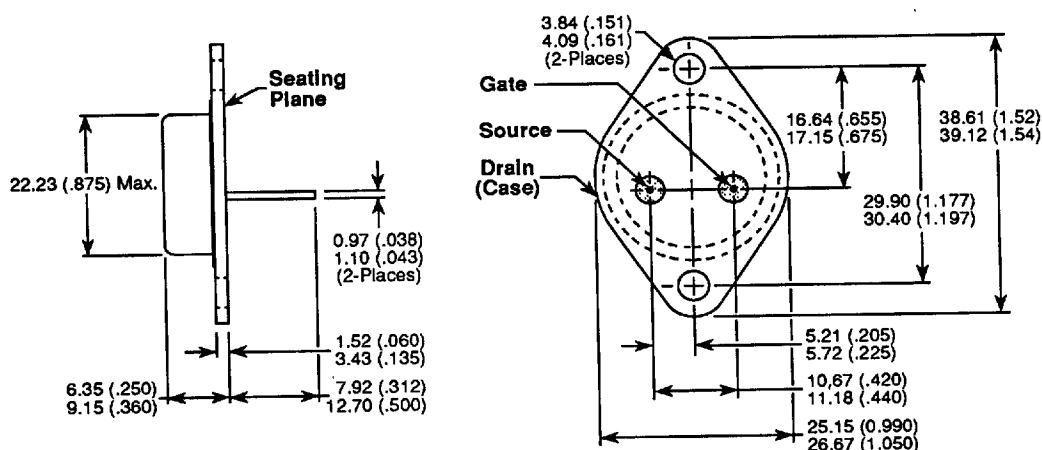


FIGURE 1, MAXIMUM EFFECTIVE TRANSIENT THERMAL IMPEDANCE, JUNCTION-TO-CASE vs PULSE DURATION





### TO-3 Package Outline (TO-204AA)



Dimensions in Millimeters and (Inches)